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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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HVD385B

Variable Capacitance Diode for VCO



ADE-208-1407A (Z)

Rev. 1 Feb. 2002

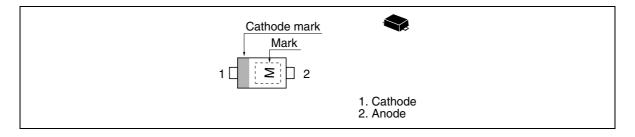
Features

- High capacitance ratio. (n = 2.43 min)
- Low series resistance. (rs = $0.75 \Omega \text{ max}$)
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

Туре No.	Laser Mark	Package Code
HVD385B	М	SFP

Pin Arrangement



HVD385B

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Reverse voltage	V _R	15	V
Junction temperature	Tj	125	٥C
Storage temperature	Tstg	–55 to +125	°C

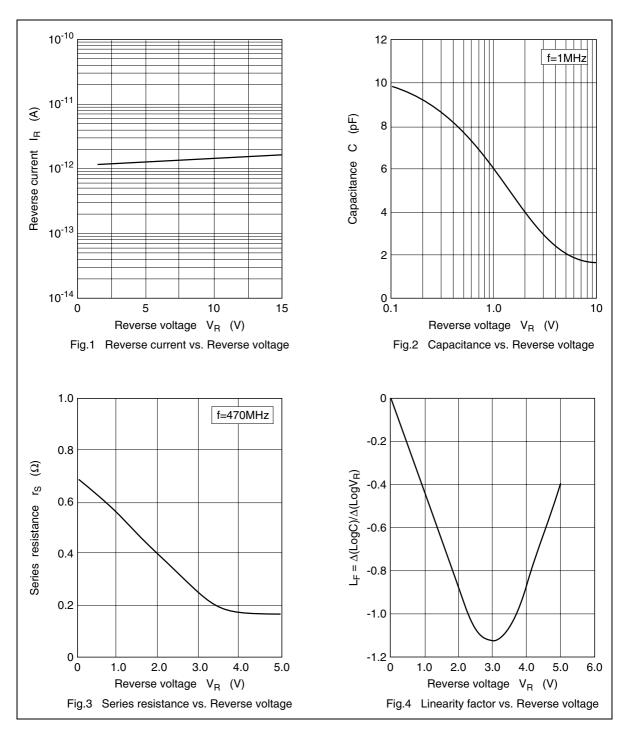
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse current	I _{R1}	_	_	10	nA	$V_{_{R}} = 10 \text{ V}$
	I _{R2}	_	_	100	_	$V_{_{\rm R}} = 10 \text{ V}, \text{ Ta} = 60^{\circ}\text{C}$
Capacitance	C _{0.5}	7.20	_	7.70	pF	$V_{_{\rm R}} = 0.5 \text{ V}, \text{ f} = 1 \text{ MHz}$
	C _{2.5}	2.70	_	3.20		$V_{_{\rm R}}$ = 2.5 V, f = 1 MHz
Capacitance ratio	n	2.43	_	2.57	_	C _{0.5} /C _{2.5}
Series resistance	r _s	_	_	0.75	Ω	$V_{_{R}} = 1 V, f = 470 MHz$

Note: Please do not use the soldering iron due to avoid high stress to the SFP package.

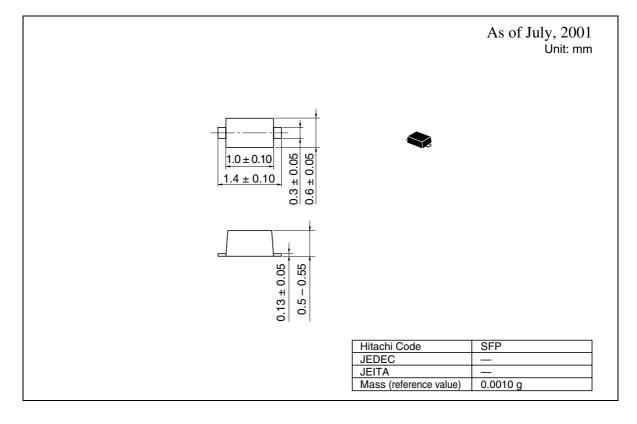
Main Characteristic



RENESAS

HVD385B

Package Dimensions





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Hitachi, Ltd.

Semiconductor & Integrated Circuits Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: (03) 3270-2111 Fax: (03) 3270-5109

URL http://www.hitachisemiconductor.com/

For further information write to:

	(America) Inc. 179 East Tasman Drive San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223	Hitachi Europe Ltd. Electronic Components Group Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 585200	Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00 Singapore 049318 Tel : <65>-538-6533/538-8577 Fax : <65>-538-6933/538-3877 URL : http://semiconductor.hitachi.com.sg	Fax : <852>-(2)-730-0281
		Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen Postfach 201, D-85619 Feldkirchen Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00	Hitachi Asia Ltd. (Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road Hung-Kuo Building Taipei (105), Taiwan Tel : <886>-(2)-2718-3160 Fax : <886>-(2)-2718-8180 Telex : 23222 HAS-TP URL : http://www.hitachi.com.tw	URL : http://semiconductor.hitachi.com.hk

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